arXiv:1211.1685v1 [hep-th] 7 Nov 2012

Domain wall description of superconductivity

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In the present work we shall address the issue of electrical conductivity in superconductors in the perspective of superconducting domain wall solutions in the realm of field theory. We take our set up made out of a dynamical complex scalar field coupled to gauge field to be responsible for superconductivity and an extra scalar real field that plays the role of superconducting domain walls. The temperature of the system is interpreted as the parameter to move type I to type II domain walls. Alternatively, this means that the domain wall surface is suffering an acceleration as one goes from one type to another. On the other hand, changing from type I to type II state means a formation of a condensate what is in perfect sense of lowering the temperature around the superconductor. One can think of this scenario as an analog of holographic scenarios where this set up is replaced by a black hole near the domain wall.

I. INTRODUCTION

Although our analysis is developed in a flat space, it enjoys some analogies with holographic superconductors that follows the well known gauge/gravity correspondence [1]. The analog of curvature here corresponds to a domain wall background that develops a condensate in its core — an idea based on superconducting strings [2] and further developed in domain walls with internal structures [3]. The type I and II domain walls are both BPS solutions and have the same Bogomol'nyi energy [4]. This means that there is no automatic way to produce an instability process in order to make one solution to decay into another. Thus the only way to deform one into another is changing the elliptic orbit that responds for the type II solution to an straight orbit that responds for the type I solution. This can be done by changing the parameters defining the elliptic orbit. As we shall see later these parameters can perfectly be reparameterized by the temperature of transition of one solution to another. Furthermore, the domain wall model is a good approximation for superconducting presenting, for instance, a layer-type perovskite-like structure [6].

The quantum field theory has emerged as a powerful alternative to explain several phenomena and its application to condensed matter physics is gaining importance, since it reveals to produce interesting results. The quantum field theory may, for example, explain some effects of superconductivity, a phenomenon of great technological applications. The results can be obtained with an appropriate quantum field theory inspired by the Ginzburg-Landau theory. As a consequence one can readily derive appropriately the London equation to explain the Meissner effect in agreement with experimental results.

In the present study, we take our set up made out of a dynamical complex scalar field coupled to gauge field to be responsible for superconductivity and an extra scalar real field that plays the role of superconducting domain walls. The temperature of the system is interpreted as the parameter to move type I to type II domain walls. Alternatively, this means that the domain wall surface is suffering an acceleration as one goes from one type to another.

II. SUPERCONDUCTING TYPE II DOMAIN WALLS SOLUTION

To obtain superconducting domain walls is needed a complex scalar field with charge q that must couple to a real scalar field that produces the domain walls. By introducing a coupling between the complex scalar field and the electromagnetic field, the former develops a *condensate* inside the domain wall which becomes superconducting and develops almost all the properties of a superconducting material. The superconducting domain wall developing a condensate can be generated by the following Lagrangian with the symmetry $Z_2 \times U(1)$:

$$\begin{aligned}\mathcal{L} &= \frac{1}{2}\partial_\mu\phi\partial^\mu\phi + (\partial^\mu\chi + iqA^\mu\chi)(\partial_\mu\chi^* - iqA_\mu\chi^*) \\ &- V(\phi,\chi,\chi^*) - \frac{1}{4}F_{\mu\nu}F^{\mu\nu}, \end{aligned} \tag{1}$$

where $\mu, \nu = 0, 1, 2, ..., d$ are bulk indices for arbitrary $(d-2)$-dimensional domain walls. We shall focus on two-dimensional domain walls with bulk indices running as $\mu, \nu = t, x, y, r$. The potential $\mathrm{V}(\phi, \chi, \chi^*)$ is chosen appropriately so that the domain wall become a superconductor

$$V(\phi,\chi,\chi^*) = \frac{1}{2}\lambda^2(\phi^2-a^2)^2 + \lambda\mu(\phi^2 \\ -a^2)\left|\chi\right|^2 + \frac{1}{2}\mu^2\left|\chi\right|^4 + \mu^2\phi^2\left|\chi\right|^2 . \tag{2}$$

The real scalar field ϕ develops Z_2 symmetry and is responsible to form the domain wall, whereas the charged scalar field χ develops a condensate inside the domain wall and also responsible to produce type II domain walls.

The equations of motion for the real and complex scalar fields coupled to electromagnetic field are given by

$$\Box\phi + \frac{\partial V}{\partial \phi} = 0, \tag{3}$$

$$\Box\chi + \frac{\partial V}{\partial \chi^*} - 2iqA_\mu\partial^\mu\chi - q^2A_\mu A^\mu\chi = 0, \qquad c.c., \tag{4}$$

$$\Box A_\mu + iq(\chi^*\partial_\mu\chi - \chi\partial_\mu\chi^*) + 2q^2A_\mu|\chi|^2 = 0. \tag{5}$$

For $A_\mu = 0$ the scalar real sector produces domain wall solutions whose kink profiles are the following well-known BPS *static* solutions obtained in terms of first order formalism and a specific superpotential [4]:

The type I solution

$$\phi(r) = -a\tanh(\lambda a r), \\ \chi = 0, \tag{6}$$

and the type II solution

$$\phi(r) = -a\tanh(2\mu a r), \\ \chi(r) = \pm a\sqrt{\frac{\lambda}{\mu} - 2}\,\mathrm{sech}\,(2\mu a r), \tag{7}$$

where r is the spatial coordinate transverse to the domain walls. These solutions correspond to straight and elliptic orbit, respectively [4] — See Fig. 1. They have the same Bogomol'nyi energy. Note that for sufficiently large λ/μ the elliptic orbit

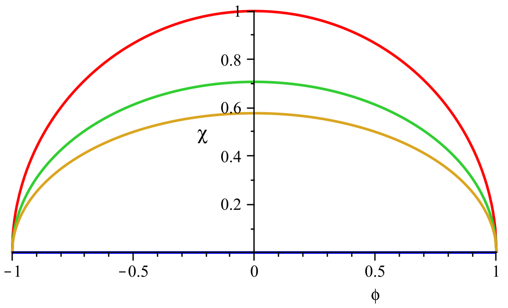

FIG. 1: Elliptic orbits followed by the type II kink. The temperature becomes high from the top ($T = 0$) to bottom ($T = T_c$) orbits.

$$\phi^2 + \left(\frac{\lambda}{\mu} - 2\right)^{-1}\chi^2 = a^2, \tag{8}$$

passes through the ‘supersymmetric vacuum’ $\phi = 0$ and $\chi = \pm\sqrt{\lambda/\mu}$ — See Fig. 1. As we shall discuss later, this will correspond to zero temperature, which agrees with the formation of a condensate inside the superconducting domain wall. On the other hand, as $\lambda/\mu \leq 2$ the type II solution does not exist anymore and the system is just governed by the type I solution which corresponds to a *non*-superconducting domain wall.

Now considering these solutions as background fields we solve the equation of motion for electromagnetic field (5) on these backgrounds. By introducing $A_\mu(t,r) = A_\mu(r)e^{-i\omega t}$ and $\chi(t,r) = \chi(r)e^{-i\theta t}$ we obtain the Schroedinger-like equation for A_x (or A_y) as follows

$$-A_x'' + \frac{1}{4}\ell^2 \mathrm{sech}^2\left(\alpha r\right) A_x = \omega^2 A_x, \tag{9}$$

where $\ell = 2\sqrt{2}qa\sqrt{\frac{\lambda}{\mu} - 2}$ and $\alpha = 2\mu a$. This is a well-known Schroedinger problem with a sech-type barrier potential whose solution is given by

$$A_x(\omega, \alpha, \ell, r) = \Big(\mathrm{sech}\left(\alpha\, r\right)\Big)^{-\frac{i\omega}{\alpha}} {}_2F_1\left[a1,\, a2;\; a3;\; \frac{1}{2}(1 - \,\tanh\left(\alpha\, r\right))\right], \tag{10}$$

where ${}_2F_1$ is a hypergeometric function with the parameters defined as

$$\begin{aligned} a1 &= \frac{1}{2}\frac{-2i\omega + \alpha + \sqrt{-\ell^2 + \alpha^2}}{\alpha}, \\ a2 &= -\frac{1}{2}\frac{2i\omega - \alpha + \sqrt{-\ell^2 + \alpha^2}}{\alpha}, \\ a3 &= -\frac{i\omega - \alpha}{\alpha}. \end{aligned} \tag{11}$$

III. THE CONDENSATE AT FINITE TEMPERATURE

Let us consider an approach in order to convince ourselves that the parameter α can be indeed related to the temperature of the system. The temperature can be interpreted as the parameter to move the type I to type II domain walls, being the latter at $0 \leq T < T_c$ and the former at $T \geq T_c$, where the condensate $<\chi>\simeq T_c\sqrt{1 - T/T_c}$ vanishes at a critical temperature T_c. Let us turn into details.

The orbits of Fig. 1 followed by the BPS solutions into the (ϕ, χ)-plane makes the type II kinks solutions to experiment *accelerations*. Alternatively, this means that the domain wall surface is suffering an acceleration as one goes from type I to type II. On the other hand, changing from type I to type II state means a formation of a condensate what is in perfect sense of lowering the temperature around the superconductor. The well-known way to relate temperature to acceleration of a surface is via Unruh effect. One can think of this scenario as an analog of holographic scenarios where this set up is replaced by a black hole near the domain wall [5].

Thus, let us now compute the analog of acceleration in the (ϕ, χ)-plane. Actually we will be indeed calculating the inverse of acceleration since the coordinates (ϕ, χ) have dimension of energy instead of length as in the usual sense. We can now define the acceleration of the system as

$$a(r_0)^{-1} = \left.\frac{d^2\chi}{d\phi^2}\right|_{r_0}, \tag{12}$$

where r_0 is some point on the bulk that for $r_0 \to 0$ produces maximal $a(r_0)^{-1}$ that means minimal acceleration and according to Unruh formula $T \sim a(r_0)$ implies minimal temperature.

The r.h.s. of Eq. (12) can be written in terms of the superpotential [4] and type II kink solutions in the form

$$\left.\frac{d^2\chi}{d\phi^2}\right|_{r_0} = \left.\frac{d}{d\phi}\left(\frac{d\chi}{d\phi}\right)\right|_{r_0} = \left.\frac{d}{d\phi}\left(\frac{W_\chi}{W_\phi}\right)\right|_{r_0} = \left.\frac{W_{\phi\chi}}{W_\phi} - \frac{W_{\phi\phi}W_\chi}{W_\phi^2}\right|_{r_0} = -\frac{\sqrt{\frac{\lambda}{\mu} - 2}}{a\,\mathrm{sech}\left(2\mu a r_0\right)}\left(1 + \frac{\lambda}{\mu}\frac{\tanh^2\left(2\mu a r_0\right)}{\mathrm{sech}^2(2\mu a r_0)}\right), \tag{13}$$

where the minus sign simply reflects the concavity of the orbits. The temperature can be now defined in the general form

$$\beta = \left|\frac{d^2\chi}{d\phi^2}\right|_{r_0}, \qquad \beta = \frac{1}{T}. \tag{14}$$

In order to identify the temperature in terms of the parameters of the theory let us investigate the regime near the core of the domain wall (i.e., in the supersymmetric vacuum $\phi = 0$ and $\chi = \pm\sqrt{\lambda/\mu}$), that is $r_0 \approx 0$ and $\lambda/\mu \gg 1$. This means that the temperature is now defined through the following equation

$$\frac{1}{T} = \frac{\sqrt{\frac{\lambda}{\mu} - 2}}{a} \approx \frac{\sqrt{\frac{\lambda}{\mu}}}{a}, \tag{15}$$

which is easily satisfied by the the dimensionless (λ, μ) and dimensionful (a) parameters

$$\lambda \sim \frac{T_c^{1/2}}{T^{1/2}}, \qquad \mu \sim \frac{1}{2}\frac{T^{1/2}}{T_c^{1/2}}, \qquad a \sim T_c^{1/2} T^{1/2}. \tag{16}$$

Notice this allows to define $\alpha = 2\mu a \equiv T$ and $\lambda a \equiv T_c$ (present in the argument of the type I solution) as we previously intended, in a natural way.

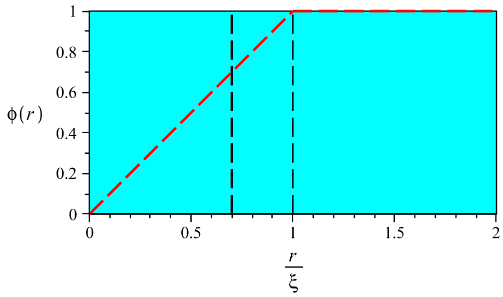

FIG. 2: The bulk and thick domain wall profile with thickness ξ. The vertical dashed-thick line stands for an arbitrary position r_0 around the core $r = 0$ (the UV-regime). Sufficiently far from the core we are in the IR-regime.

Let us now consider a region out of the core, Fig. 2, that is $2\mu a r_0 \ll 1$ and $\lambda/\mu \gg 1$. Now substituting these assumptions into (13) we obtain the temperature

$$T = \frac{a(\lambda/\mu)^{-3/2}}{(2\mu a r_0)^2}. \tag{17}$$

Now the temperature has a dependence with four parameters. However, we shall keep defining $\alpha = 2\mu a \equiv T$ and $\lambda a \equiv T_c$ as in the previous analysis. Thus, substituting again the parameters (16) into the temperature (17) we readily find a relation between the critical temperature T_c and the scale r_0 given by

$$T = \frac{1}{2^{3/2} T_c r_0^2}. \tag{18}$$

Since by definition the temperature T does not depend on r_0 then

$$T_c r_0^2 = const., \tag{19}$$

which suggests that large r_0 stands for superconductors of low critical temperature that are well described by BCS theory, whereas small r_0 stands for High-T_c superconductors [6]. We are still tempted to write this formula in terms of atomic mass A in the bulk since the nuclear radius can be well approximated by $r_0 \simeq A^{1/3}\, fm$. Thus we arrive to the well-known *isotopic formula*

$$T_c A^{2/3} = const. \tag{20}$$

The condensate can be easily isolated by power expanding the scalar solution $\chi(r)$ in Eq. (7) around the core of the type II domain walls at $r\approx 0$ as

$$\chi(r)=m-\frac{1}{2}m\alpha^2r^2+..., \tag{21}$$

with the condensate given by $<\chi>\simeq m$. We have written the original type II solution as $\phi(r)=-a\tanh\alpha r$, $\chi(r)=m\,\mathrm{sech}\,\alpha r$. Notice that for the type II solution to flow up to type I solution the parameters m,α should scale as $m\to 0$ with $\alpha\equiv T\to T_c$, which perfectly agree with a vanishing condensate $<\chi>\simeq m$, as anticipated.

To find the explicit dependence of the condensate with the temperature we should recall the original form of the parameters m,α, that is

$$m=a\sqrt{\frac{\lambda}{\mu}-2},\qquad \alpha=2\mu a. \tag{22}$$

Now substituting (16) into (22) allows us to obtain

$$m=\sqrt{2}T_c\sqrt{1-\frac{T}{T_c}}, \tag{23}$$

which condensate has precisely the desired form $<\chi>\simeq m=\sqrt{2}T_c\sqrt{1-T/T_c}$. We also note that from the equation of motion of electromagnetic field A_x the *effective condensate* 'seen' by the electromagnetic field is given in terms of the charge q, i.e., $<\chi>_{eff}\simeq\ell=2\sqrt{2}\,q\,m$ or simply $<\chi>_{eff}\simeq 4\,q\,T_c\sqrt{1-T/T_c}$ — See Fig. 3 for the explicit behavior of the condensates $<\chi>$ and $<\chi>_{eff}$ with the temperature. The divergence of the condensate with the charge $q\to\infty$ as $T/T_c\to 0$ has been pointed in holographic superconductors as a consequence of the *probe limit*.

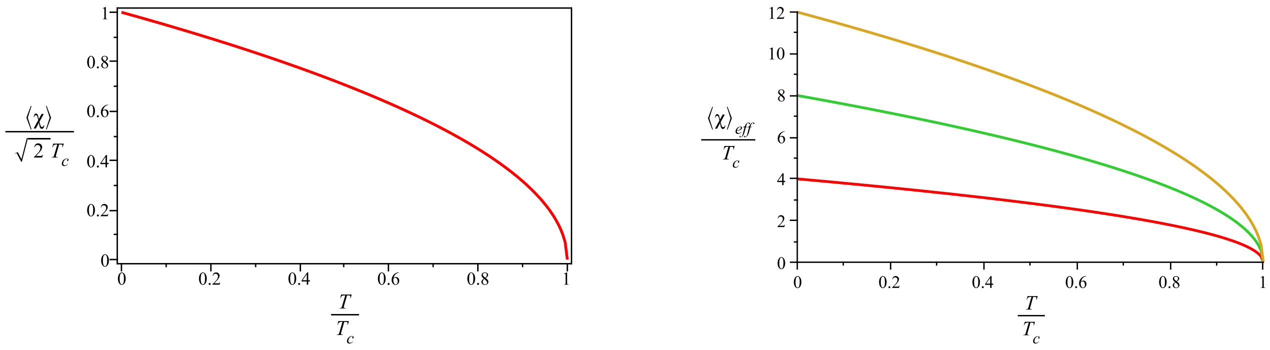

FIG. 3: (*Left panel*) The condensate as a function of the temperature. (*Right panel*) The effective condensate as a function of temperature for charges $q=1,2,$ and 3 from bottom to top.

IV. CONDUCTIVITY

As well-known, from the Ohm's law we can readily obtain the conductivity along a direction, say x-direction along the domain walls, in the form

$$\sigma_x(x,y)=\frac{J_x}{E_x}=\frac{A_x'(0)}{i\omega A_x(0)}, \tag{24}$$

where in the last step we used $E_x=-\partial_tA_x=i\omega A_x$, with $A_x(t,r)=A_x(r)e^{-i\omega t}$ and defined the current as $J_x=A_x'(0)$. In the holographic perspective, the latter definition can be justified by power expanding the electromagnetic field $A_x(t,r)$ around the core of the type II domain walls at $r\approx 0$, that is the place where the condensate forms, as follows

$$A_x(r)=A_x(0)+A_x'(0)\,r+... \tag{25}$$

Although this is a common knowledge in holographic superconductors, here we shall not explicitly attempt to interpret this as a holographic assumption. Instead, we use the boundary conditions for the electromagnetic field on an interface at $r = 0$ (or in other position as we shall consider later) that corresponds to a plane along the superconducting domain wall. More specifically, the boundary conditions for the magnetic field at an interface is

$$\hat{n} \times \vec{B} = \vec{J}, \qquad \text{at } r = 0 \tag{26}$$

where $\hat{n}$ is a normal vector to the surface of the domain wall and $\vec{J}$ is a surface current. For $\hat{n} = (0, 0, 1)$ and $\vec{A} = (A_x, A_y, 0)$ the boundary condition (26) simply becomes

$$-\,\partial_r A_x(r) = J_x, \qquad \text{at } r = 0 \tag{27}$$

which is nothing but our anticipated assumption $J_x = A'_x(0)$ that in the present case it is trustable even outside the holographic realm.

Now using the solution (10) for the electromagnetic field and power expanding it as in (25) around a generic point $r \approx \delta$) (sames as r_0) we are able to write the explicit form of the conductivity $\sigma_x = \sigma_y \equiv \sigma$ as follows

$$\sigma(\omega, \alpha, \ell, \delta) = \frac{\frac{1}{8}\, i \left(4\,\omega^2 + 4\, i\omega\, \alpha - \ell^2\right) {}_2F_1\left[b1,\, b2;\; b3;\; \frac{1}{2}(1 -\, \tanh{(\alpha\, \delta)})\right] \mathrm{sech}^2\,(\alpha\, \delta)}{\omega\ (i\omega - \alpha)\, {}_2F_1\left[a1,\, a2;\; a3;\; \frac{1}{2}(1 -\, \tanh{(\alpha\, \delta)})\right]} + \tanh{(\alpha\, \delta)}\,, \tag{28}$$

with the parameters $b1, b2$ and $b3$ defined as

$$\begin{aligned} b1 &= -\frac{1}{2}\frac{2i\omega - 3\alpha + \sqrt{-\ell^2 + \alpha^2}}{\alpha}, \\ b2 &= \frac{1}{2}\frac{-2i\omega + 3\alpha + \sqrt{-\ell^2 + \alpha^2}}{\alpha}, \\ b3 &= -\frac{i\omega - 2\alpha}{\alpha}. \end{aligned} \tag{29}$$

Recall we have previously defined the temperature $\alpha \equiv T$ and the condensate $m \simeq < \chi >$. We now consider the conductivity normalized by the ‘effective condensate’ $\ell \to q\ell$, such that we define $\alpha = q^{-1} q\, \ell$ and $\omega = \omega_r q\, \ell$ into σ. We can still write $\frac{\alpha}{q<\chi>_{eff}} = q^{-1}$ and $\frac{\omega}{q<\chi>_{eff}} = \omega_r$ (reduced frequency). Finally we substitute all over this into (28)-(29). The results have shown that for $\delta \approx 0$ the optical conductivity — See Fig. 4 — is essentially the same as the one computed at $r = 0$, i.e., at the core of the domain wall. On the other hand, as we shall see later, the conductivity (or AC resistivity) as a function of the temperature is more sensitive to the values of δ. In the following we focus on further characteristics of the optical conductivity by simply assuming $\alpha\delta = 0$.

As $\omega \to 0$ and $T \to 0$ the conductivity (28) approaches a delta function $\delta(\omega)$. This is because for $T \to 0$, we have $\ell \sim T_c$. Thus, in this limit, $\alpha^2 \ll \ell^2$ and $\omega^2 \ll \ell^2$ implies that the real and imaginary parts of the conductivity, up to a prefactor $\sim 2\alpha/\ell$ from the hypergeometric functions, can be written as

$$\mathrm{Re}\,\sigma(\omega) \propto \frac{(\ell/\alpha)^2}{(\omega/\alpha)^2 + 1} \to \delta(\omega), \qquad \mathrm{Im}\,\sigma(\omega) \propto \frac{(\ell/\alpha)^2}{(\omega/\alpha)^3 + \omega/\alpha} \to \frac{\ell^2}{\alpha}\frac{1}{\omega}. \tag{30}$$

Note that the distribution in real part of (30) tends to a delta function, whereas the imaginary part presents a pole. This in accord with the Kramers-Kronig relations and Drude model of conductor in the limit of the relaxation time due to scattering $\tau \to \infty$ (superconductor). We conclude from such discussion that the limit $\omega \to 0$ at $T \to 0$ our model presents an infinite DC conductivity as expected for a superconductor.

Now let us consider the conductivity as a function of the temperature. Repeating the previous analysis for $\alpha\delta \to \infty$ the argument in the hypergeometric functions goes to zero as $e^{-2\alpha\delta}$. In this regime the ratio of the hypergeometric functions in the conductivity formula can be well approximated by a series of a few terms. By keeping only leading and next-to-leading terms we find

$$\mathrm{Re}\,\sigma(\omega, \alpha) \propto \delta(\omega)\left(1 - \frac{1}{8}\frac{\ell^2}{\alpha^2}e^{-2\alpha\delta} + ...\right) \simeq \delta(\omega) e^{-\frac{1}{8}\left(\frac{\Delta}{\alpha}\right)^2}, \tag{31}$$

where

$$\Delta = \ell e^{-\alpha\delta}, \tag{32}$$

precisely defines the binding energy of a Cooper pair as long as we identify $\ell = 2\omega_D$ as the Debye temperature and $\delta\alpha = 1/VN_F$, being $V > 0$ the binding potential and N_F the density of orbitals with Fermi's energy. Note that the

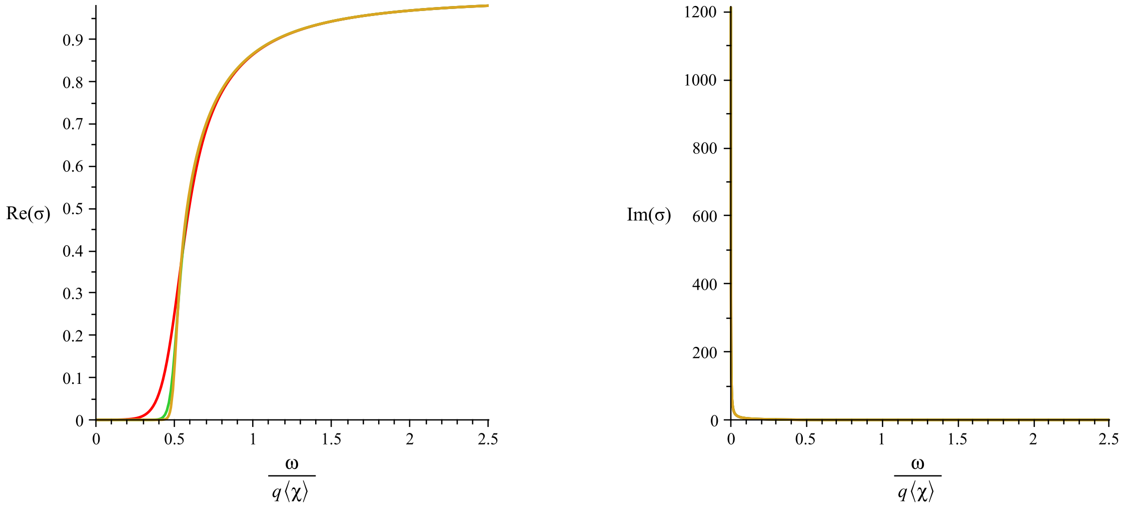

FIG. 4: (*Left panel*) The real part of the conductivity as a function of the frequency normalized by the effective condensate. (*Right panel*) The imaginary part of the conductivity as a function of the frequency normalized by the effective condensate. In both cases we use the charges $q = 8, 20$, and 32 from top to bottom; $\delta = 0.01$ and $\ell \simeq < \chi >_{eff} = 4$.

limit $\delta\alpha \to \infty$ corresponds to $VN_F \to 0$ that is the limit of weak coupling that is in accord with the BCS theory. On the other hand, the limit $\delta\alpha \to 0$ corresponds to $VN_F \to \infty$ that is the limit of strong coupling and represents the superconductors of high critical temperature called "High-Tc superconductors" such as cuprate superconductors.

In order to go further on our analysis we extend the power expansion of the condensate in (21) to the expansion around a plane $r \approx \delta$, Fig. 2, parallel to the domain wall near its center given by

$$\chi(r) = m\,\text{sech}(\alpha\delta) - m\,\text{sech}(\alpha\delta)\tanh(\alpha\delta)\alpha(r-\delta) + ..., \tag{33}$$

which allows us to redefine the usual condensate previously studied in the form $< \chi > \simeq m\,\text{sech}\,(\alpha\delta) = \sqrt{2}T_c\sqrt{1-T/T_c}\,\text{sech}\,(\alpha\delta)$ and the effective condensate as $< \chi >_{eff} \simeq \ell\,\text{sech}\,(\alpha\delta) = 2\sqrt{2}\,q\,m\,\text{sech}\,(\alpha\delta)$ or simply $< \chi >_{eff} \simeq 4qT_c\sqrt{1-T/T_c}\,\text{sech}\,(\alpha\delta)$. In the regime $\alpha\delta \to \infty$, particularly, we write the effective condensate given by

$$< \chi >_{eff} \simeq 2\ell e^{-\alpha\delta}. \tag{34}$$

The equations (32) and (34) now allow us to write the important relation

$$\frac{2\Delta}{T_c} = \frac{< \chi >_{eff}}{T_c}. \tag{35}$$

Recall the examples in Fig. 3 for the effective condensate for three distinct charges in the regime $\alpha\delta \to 0$ previously considered. Using the Eq. (35) we identify the relations between binding energy and the critical temperature given by $2\Delta \simeq 4\,T_c$, $2\Delta \simeq 8\,T_c$ e $2\Delta \simeq 12\,T_c$.

This seems to point out a behavior of High-T_c superconductors. For the sake of comparison we know that BCS superconductors have a typical relation $2\Delta \simeq 3.5\,T_c$, whereas the High-T_c superconductors normally enjoy the relation $2\Delta \simeq 5\,T_c$ to $2\Delta \simeq 8\,T_c$.

Before ending this discussion, we present a relation between the positions $r \simeq \delta$ in relation to the core of the condensate at $r \approx 0$ for BCS and High-T_c superconductors. In doing this, we take the ratio between the respective binding energies Δ defined in (32) and solve it for a ratio in terms of δ in the form

$$\frac{\delta_{BCS}}{\delta_{HT_c}} = 1 - \frac{1}{\alpha\delta_{HT_c}} \ln\frac{\Delta_{BCS}}{\Delta_{HT_c}}. \tag{36}$$

Since $\Delta_{BCS} < \Delta_{HT_c}$, in the limit where $\alpha\delta_{HT_c} \ll 1$, as expected for High-$T_c$ superconductors (with 'very high' T_c), we find $\delta_{BCS} \gg \delta_{HT_c}$. In a more realistic example, for $\alpha\delta_{HT_c} = 1$, $\Delta_{BCS} = 3.5T_c$ and $\Delta_{HT_c} = 8T_c$ we find $\delta_{BCS} \simeq 1.83\delta_{HT_c}$. This should be related to different positions along the bulk (i.e., the thickness of the domain wall) displayed in Fig. 2.

In the following we present the plot that describes the behavior of the real part of the low frequency AC resistivity $\rho = 1/\sigma$ as a function of the temperature — Fig. 5. Notice that for the resistivity sufficiently above the critical

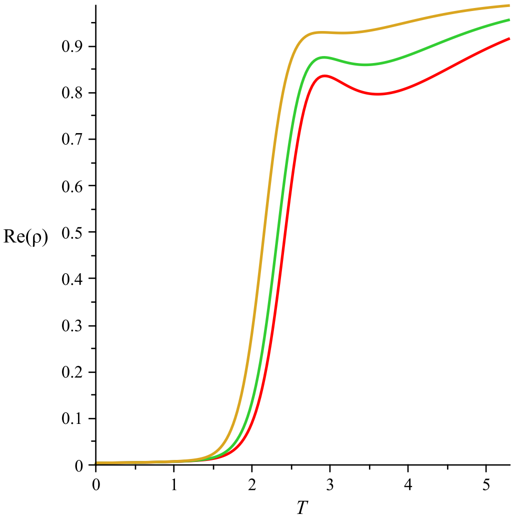

FIG. 5: The real part of the AC resistivity at low frequencies as a function of temperature. We use $\delta = 0.40$, 0.45, and 0.55, from bottom to top; $T_c = 3$, $\omega = 0.8$ and $q = 1$.

temperature T_c decreases almost linearly with the temperature. Moreover, as the system approaches the critical temperature, the resistivity tends to locally increases, but decreases very quickly below the critical temperature until achieve the resistivity very close to zero. This should be compared with the resistivity versus temperature for three High-T_c superconductor samples of La-Ba-Cu-O with $T_c = 35^o K$ by Bednorz and Müller [6].

We still note that for values of δ larger than 0.40 the system tends to reduce its critical temperature — see Fig. 5, the plots for $\delta = 0.45$ and $\delta = 0.55$. This phenomenon we have anticipated in our previous discussions around the Eq. (36).

Finally, as a last comment we can even improve our above discussions by considering more general orbits. The original idea of trial orbit method [4] enables us extending the aforementioned elliptic orbit to general orbits

$$\phi^2 + \left(\frac{\lambda}{\mu} - 2\right)^{-1} \chi^n = a^2. \tag{37}$$

Although much harder to deal with, this system will produce more general type I and type II solutions in such a way that the condensate may have a more general power

$$< \chi > \simeq T_c \left(1 - \frac{T}{T_c}\right)^{1/n}, \tag{38}$$

just as higher dimensional operators in the holographic set up [5]. This extension may reveal an even more realistic analysis for considering domain wall description of superconductivity.

V. CONCLUSIONS

In this paper, by considering domain wall description of superconductivity, we have identified a relationship between the binding energy of Cooper pairs and the effective condensate depending on the temperature and the electrical charge. For charges large enough we get a typical ratio of High-T_c superconductors. We calculate the optical conductivity and show that in the regime of low temperatures and frequencies we get a zero infinite DC conductivity. We conclude that the low frequency AC resistivity as a function of temperature is similar to what happens in High-T_c superconductors. The critical temperature tends to be reduced when we move far from the condensate via the deviation position δ. As future prospects, we intend to attack the problem by investigating other quantities such as the London penetration depth and upper critical field H_{c2} as a function of temperature and effects of anisotropy within the domain walls.

It seems that the gap (or pairing mechanism) $\sigma \sim \exp(-\Delta/T)$ opens for $\omega \sim 0, T \sim 0$ as one evaluates the wave function A_x at $r \sim \delta$, where δ is some place around but not in the core of the domain wall. This may also suggest some new set up to study holographic superconductivity by considering both the boundary and an infrared cutoff to produce the gap. Although we have essentially considered Bloch wall type solution, our analysis can be easily extended to other domain wall solutions with internal structures to study many other possibilities such as different superconducting phases. An even more realistic behavior can also be found for non-elliptic orbits $\phi^2 + B\chi^n = a^2$.

Acknowledgments

We would like to thank CNPq, CAPES, PNPD/PROCAD - CAPES for partial financial support.

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